



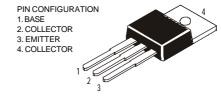


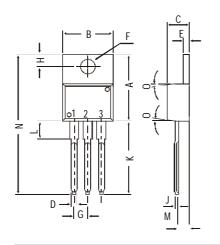
TO-220 Plastic Package

CSB857, CSB858 CSD1133, CSD1134

CSB857, 858 PNP PLASTIC POWER TRANSISTORS CSD1133, 1134 NPN PLASTIC POWER TRANSISTORS

Low frequency Power Amplifier





| DIM | MIN. | MAX. | |
|-----|-----------------------|---|--|
| Α | 14.42 | 16.51 | |
| В | 9.63 | 10.67 | |
| С | 3.56 | 4.83 | |
| D | | 0.90 | |
| Ε | 1.15 | 1.40 | |
| F | 3.75 | 3.88 | |
| G | 2.29 | 2.79 | |
| Н | 2.54 | 3.43 | |
| J | | 0.56 | |
| K | 12.70 | 14.73 | |
| L | 2.80 | 4.07 | |
| М | 2.03 | 2.92 | |
| N | | 31.24 | |
| 0 | DEG 7 | | |
| | A B C D E F G H J K L | A 14.42 B 9.63 C 3.56 D E 1.15 F 3.75 G 2.29 H 2.54 J K 12.70 L 2.80 M 2.03 N | |

ABSOLUTE MAXIMUM RATINGS

| | | 857 1133 | | 858 1134 | |
|---|---------------|-------------|-----------|-------------|--|
| | | | | | |
| Collector-base voltage (open emitter) | V_{CBO} | max. | 70 | | 70 V |
| Collector-emitter voltage (open base) | $V_{C\!E\!O}$ | max. | <i>50</i> | | 60 V |
| Collector current | I_C | max. | | 4.0 | \boldsymbol{A} |
| Total power dissipation up to $T_C = 25^{\circ}C$ | P_{tot} | max. | | 40 | W |
| Junction temperature | T_{i} | max. | | <i>150</i> | ${}^{\!$ |
| Collector-emitter saturation voltage | , | | | | |
| $I_C = 2 A$; $I_B = 200 \text{ mA}$ | V_{CEsat} | max. | | 1.0 | V |
| D.C. current gain | | | | | |
| $I_C = 1 A$; $V_{CE} = 4 V$ | $h_{\!F\!E}$ | min. | | 60 | |
| - | | max. | | 320 | |

RATINGS (at T_A =25°C unless otherwise specified) Limiting values

| Limiting values | | 857 | <i>858</i> | |
|---------------------------------------|---------------|-------------|-------------|--|
| _ | | <i>1133</i> | <i>1134</i> | |
| Collector-base voltage (open emitter) | V_{CBO} | max. 70 | 70 V | |
| Collector-emitter voltage (open base) | $V_{C\!E\!O}$ | max. 50 | 60 V | |
| Emitter-base voltage (open collector) | V_{EBO} | max. | 5.0 V | |

CSB857, CSB858 CSD1133, CSD1134

| Callacton summent | | I.a | | 1 | .0 | A |
|--|-----------|----------------|---------------|----------------|------------|---------------|
| Collector current (Pools volve) | | I _C | max. | | .0 .0 | A |
| Collector current (Peak value) | | I_C | max. | - | .u 10 | W |
| Total power dissipation up to | IC = 23 C | P_{tot} | max. | - | | • • |
| Junction temperature | | T_j | max. | 13 | | \mathcal{C} |
| Storage temperature | | T_{stg} | −65 to +150 ° | | C | |
| CHARACTERISTICS | | | | | | |
| $T_{amb} = 25^{\circ}C$ unless otherwise | specified | | | | | |
| | • | | | <i>857 858</i> | | ? |
| | | | 1133 1134 | | ! | |
| Collector cutoff current | | | | | | |
| $I_E = 0$; $V_{CB} = 50V$ | | I_{CBO} | max. | 1. | .0 | μA |
| Breakdown voltages | | | | | | |
| $I_C = 50 \text{ mA}; I_B = 0$ | | $V_{C\!E\!O}$ | min. | <i>50</i> | 60 | V |
| $I_C = 10 \ \mu A; I_E = 0$ | | V_{CBO} | min. | 7 | 70 | V |
| $I_E = 10 \ \mu A; I_C = 0$ | | V_{EBO} | min. | 5 | .0 | V |
| Saturation voltage | | | | | | |
| $I_C = 2 A; I_B = 0.2 A$ | | V_{CEsat}^* | max. | 1. | .0 | V |
| Base emitter on voltage | | | | | | |
| $I_C = 1 A$; $V_{CE} = 4 V$ | | $V_{BE(on)}^*$ | max. | 1. | .0 | V |
| D.C. current gain | | | | | | |
| $I_C = 0.1 A; V_{CE} = 4 V$ | | hFE* | min. | á | 35 | |
| $I_C = 1.0 \text{ A}; V_{CE} = 4 V^{**}$ | | hFF* | min. | ϵ | 3 <i>0</i> | |
| | | | max. | 32 | 20 | |
| Transition frequency | | | | | | |
| $I_C = 0.5 A; V_{CE} = 4 V$ | PNP | f_T | typ. | i | 15 | MHz |
| - - | NPN | • | typ. | 7. | .0 | MHz |
| | | | J 1 | | | |

^{**} hfe classification: B: 60-120 C: 100-200 D: 160-320

^{*} Pulse test

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